

TO 3
CASE

30 Amp Center Tapped Silicon Integrated Rectifiers

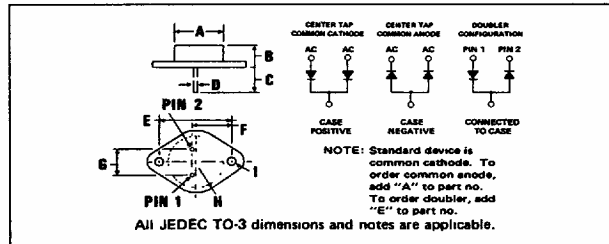
Controlled Avalanche Types with 250V,
450V, and 650V Minimum Avalanche Ratings

Non-Controlled Avalanche Types with
100V, 200V, 400V and 600V V_{RRM} Ratings

High Cycle Surge Current

Fast Recovery Types with 200 Nanosecond Maximum t_{rr}

LTR.	INCHES	MILLIMETERS
A	.73-.77 Dia.	18,54-19,56 Dia.
B	.323-.342	8,20-8,69
C	.40 Min.	10,16
D	.038-.043 Dia.	.97-1,09
E	1.180-1.194	29,97-30,33
F	.665-.675	16,89-17,15
G	.426-.440	10,82-11,18
H	.525R Max.	13,34R
I	.151-.161 Dia.	3,34-4,09



MAXIMUM RATINGS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

RATINGS	SYMBOL	CONTROLLED AVALANCHE				NON-CONTROLLED AVALANCHE				FAST RECOVERY TIME				UNITS
		R702	R704	R706	R711	R712	R714	R716	R711X	R712X	R714X	R716X		
Series Number														
DC Blocking Voltage	V_{RM}	200	400	600	100	200	400	600	100	200	400	600	Volts	
Working Peak Reverse Voltage	V_{RWM}													
Peak Repetitive Reverse Voltage	V_{RRM}													
RMS Reverse Voltage	V_{RRMS}	140	280	420	70	140	280	420	70	140	280	420	Volts	
Power Dissipation in V_{RRM} Region for 100 μ sec Square Wave (Per diode)	P_{RM}	1500				NA				NA				Watts
Continuous Power Dissipation in V_{RRM} Region at $T_C = 100^\circ\text{C}$ (Per diode)	P_R	4				NA				NA				Watts
Peak Surge Current, 1/2 Cycle at 60 Hz, (Non-Rep) and $T_C = 100^\circ\text{C}$ (Per diode) (Fig. 2)	I_{FSM}	300				150				50				Amps
Peak Surge Current, 1 sec at 60 Hz and $T_C = 100^\circ\text{C}$ (Per diode) (Fig. 2)	I_{FRM}	60				15				- 65 to + 150				$^\circ\text{C}$
Avg. Forward Current at $T_C = 100^\circ\text{C}$ (Per diode)	I_O	375				95				Amps ² -Sec.				
Junction Operating and Storage Temperature Range	T_J, T_{STG}	375				95								
Fusing Data	I^2T	375				95								

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ unless otherwise noted)

CHARACTERISTICS	SYMBOL	CONTROLLED AVALANCHE				NON-CONTROLLED AVALANCHE				FAST RECOVERY TIME				UNITS
		R702	R704	R706	R711	R712	R714	R716	R711X	R712X	R714X	R716X		
Series Number														
Minimum Avalanche Voltage	V_{BR}	250	450	650	NA				NA				Volts	
Maximum Avalanche Voltage	V_{BR}	700	900	1100	NA				NA				Volts	
Maximum Instantaneous Forward Voltage Drop (Per diode) at 15 Amps (Fig. 3)	V_{FM}	1.2				1.4				1.4				Volts
Maximum Reverse Current at Rated V_{RM} at $T_C = 100^\circ\text{C}$	I_{RM}	1				5				200				mA
Maximum Reverse Recovery Time at $I_F = 1A, I_R = 2A, I_{RR} = 0.5$ Amp	t_{rr}	NA				200				1.5				nsec
Maximum Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.5				1.5								$^\circ\text{C}/\text{W}$

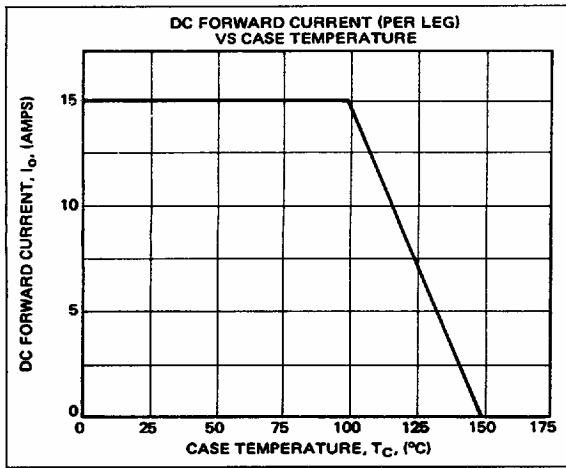


FIGURE 1

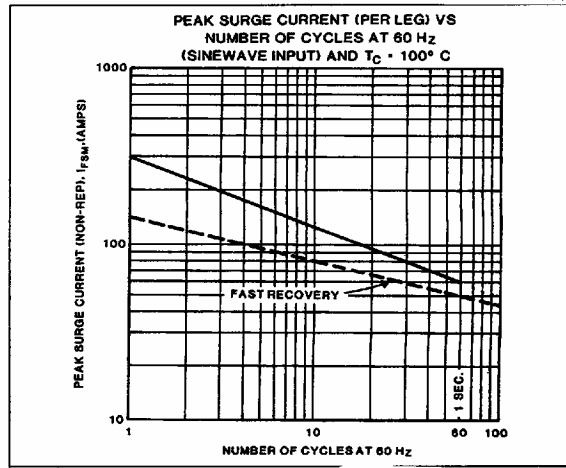


FIGURE 2

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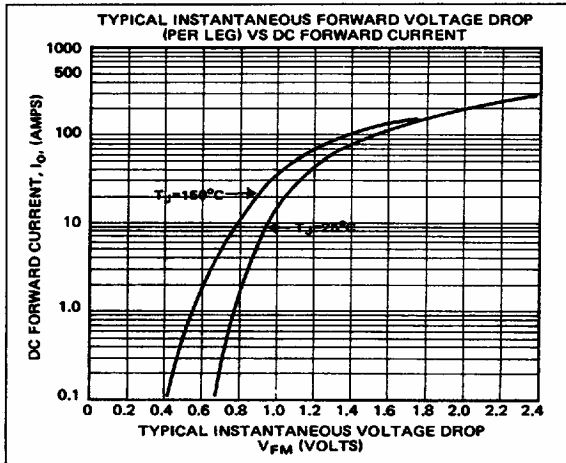


FIGURE 3

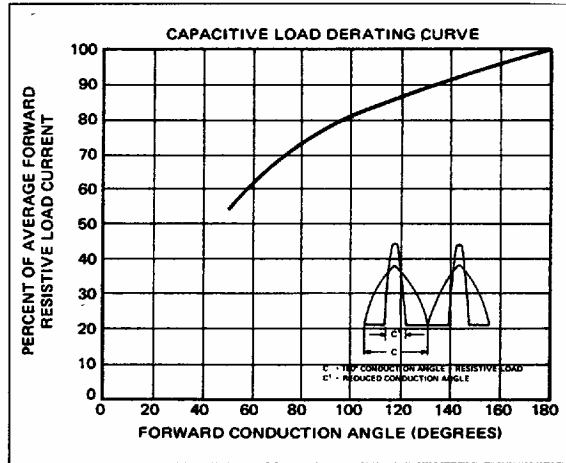


FIGURE 4

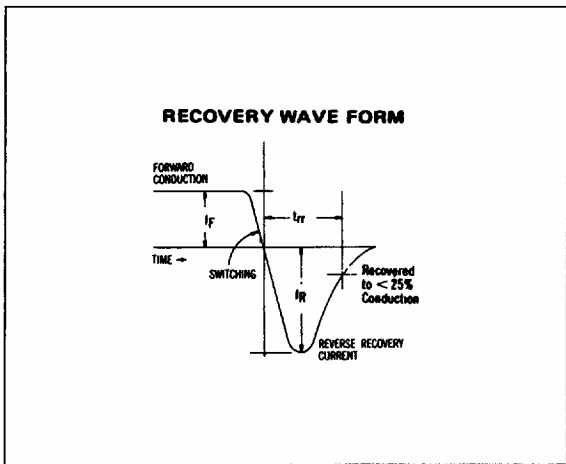


FIGURE 5